

# Abdelilah Slaoui

## List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

68

papers

777

citations

16

h-index

26

g-index

74

ext. papers

900

ext. citations

3.8

avg, IF

3.66

L-index

#	Paper	IF	Citations
68	Synthesis and characterization of silicon clathrates of type I Na <sub>8</sub> Si <sub>46</sub> and type II Na <sub>x</sub> Si <sub>136</sub> by thermal decomposition. <i>Journal of Alloys and Compounds</i> , <b>2022</b> , 903, 163967	5.7	0
67	SnO <sub>2</sub> Films Elaborated by Radio Frequency Magnetron Sputtering as Potential Transparent Conducting Oxides Alternative for Organic Solar Cells. <i>ACS Applied Energy Materials</i> , <b>2022</b> , 5, 170-177	6.1	0
66	Properties of Yb-added ZnO (Yb:ZnO) films as an energy-conversion layer on polycrystalline silicon solar cells. <i>Materials Chemistry and Physics</i> , <b>2021</b> , 265, 124513	4.4	1
65	Study of hybrid organic/inorganic halide perovskite solar cells based on MAI[(PbI <sub>2</sub> ) <sub>1-x</sub> (CuI) <sub>x</sub> ] absorber layers and their long-term stability. <i>Journal of Materials Science: Materials in Electronics</i> , <b>2021</b> , 32, 20684-20697	2.1	1
64	Photovoltaics: Advanced Inorganic Materials <b>2021</b> , 5-16		
63	Silicon Clathrate Films for Photovoltaic Applications. <i>Journal of Physical Chemistry C</i> , <b>2020</b> , 124, 14972-14977	4.97	5
62	Yb-doped zinc tin oxide thin film and its application to Cu(InGa)Se <sub>2</sub> solar cells. <i>Journal of Alloys and Compounds</i> , <b>2020</b> , 815, 152360	5.7	5
61	Polyethylenimine-Ethoxylated Interfacial Layer for Efficient Electron Collection in SnO <sub>2</sub> -Based Inverted Organic Solar Cells. <i>Crystals</i> , <b>2020</b> , 10, 731	2.3	5
60	Photon management properties of Yb-doped SnO nanoparticles synthesized by the sol-gel technique. <i>Physical Chemistry Chemical Physics</i> , <b>2019</b> , 21, 21407-21417	3.6	13
59	Cu(InGa)Se <sub>2</sub> Solar Cell Efficiency Enhancement Using a Yb-Doped SnO <sub>x</sub> Photon Converting Layer. <i>ACS Applied Energy Materials</i> , <b>2019</b> , 2, 5094-5102	6.1	7
58	Thickness Dependence and Strain Effects in Ferroelectric Bi <sub>2</sub> FeCrO <sub>6</sub> Thin Films. <i>ACS Applied Energy Materials</i> , <b>2019</b> , 2, 8550-8559	6.1	5
57	EFFECT OF POTASSIUM CYANIDE ETCHING ON STRUCTURAL, OPTICAL AND ELECTRICAL PROPERTIES OF Cu <sub>2</sub> ZnSnS <sub>4</sub> THIN FILMS DEPOSITED BY A MODIFIED SPRAY PROCESS. <i>Surface Review and Letters</i> , <b>2019</b> , 26, 1950053	1.1	
56	Low-temperature growth and electronic structures of ambipolar Yb-doped zinc tin oxide transparent thin films. <i>Applied Surface Science</i> , <b>2018</b> , 441, 49-54	6.7	5
55	Band-Gap Tuning in Ferroelectric Bi <sub>2</sub> FeCrO <sub>6</sub> Double Perovskite Thin Films. <i>Journal of Physical Chemistry C</i> , <b>2018</b> , 122, 1070-1077	3.8	22
54	Investigation of LaVO <sub>3</sub> based compounds as a photovoltaic absorber. <i>Solar Energy</i> , <b>2018</b> , 162, 1-7	6.8	15
53	Absorption Enhancement in Thin-Film Solar Cells with Perforated Holes. <i>Plasmonics</i> , <b>2018</b> , 13, 939-945	2.4	1
52	Sodium doping mechanism on sol-gel processed kesterite Cu <sub>2</sub> ZnSnS <sub>4</sub> thin films. <i>Superlattices and Microstructures</i> , <b>2018</b> , 120, 747-752	2.8	10

51	Macroporosity Enhancement of Scaffold Oxide Layers Using Self-Assembled Polymer Beads for Photovoltaic Applications. <i>Physica Status Solidi (A) Applications and Materials Science</i> , <b>2018</b> , 215, 1700946 <sup>1.6</sup>		
50	Tuning photovoltaic response in BiFeCrO films by ferroelectric poling. <i>Nanoscale</i> , <b>2018</b> , 10, 13761-13766 <sup>7.7</sup>	20	
49	Silicon Tunnel Junctions Produced by Ion Implantation and Diffusion Processes for Tandem Solar Cells. <i>IEEE Journal of Photovoltaics</i> , <b>2018</b> , 8, 1436-1442	3.7	2
48	Light emitting mechanisms in Si-rich SiN <sub>x</sub> films with different silicon nitride stoichiometry. <i>Physica Status Solidi (B): Basic Research</i> , <b>2017</b> , 254, 1600670	1.3	4
47	EuIII-Based Nanolayers as Highly Efficient Downshifters for CIGS Solar Cells. <i>European Journal of Inorganic Chemistry</i> , <b>2017</b> , 2017, 5318-5326	2.3	7
46	Nd-Doped SnO <sub>2</sub> and ZnO for Application in Cu(InGa)Se <sub>2</sub> Solar Cells. <i>Science of Advanced Materials</i> , <b>2017</b> , 9, 2114-2120	2.3	10
45	Tuning the chemical properties of europium complexes as downshifting agents for copper indium gallium selenide solar cells. <i>Journal of Materials Chemistry A</i> , <b>2017</b> , 5, 14031-14040	13	26
44	Structural, optical and electrical properties of Nd-doped SnO <sub>2</sub> thin films fabricated by reactive magnetron sputtering for solar cell devices. <i>Solar Energy Materials and Solar Cells</i> , <b>2016</b> , 145, 134-141	6.4	42
43	Enhancement of Copper Indium Gallium Selenide Solar Cells Using Europium Complex as Photon Downshifter. <i>Advanced Optical Materials</i> , <b>2016</b> , 4, 1846-1853	8.1	15
42	Kesterite / wurtzite Cu <sub>2</sub> ZnSnS <sub>4</sub> nanocrystals: Synthesis and characterization for PV applications <b>2016</b> ,		2
41	Properties of Cu <sub>2</sub> ZnSnS <sub>4</sub> films elaborated by modified spray process <b>2016</b> ,		1
40	Photon management properties of rare-earth (Nd,Yb,Sm)-doped CeO <sub>2</sub> films prepared by pulsed laser deposition. <i>Physical Chemistry Chemical Physics</i> , <b>2016</b> , 18, 2527-34	3.6	6
39	High-k MNOS-Like Stacked Dielectrics for Non-Volatile Memory Application. <i>Journal of Nano Research</i> , <b>2016</b> , 39, 121-133	1	
38	Thickness effect on Cu <sub>2</sub> ZnSnS <sub>4</sub> properties using non-toxic and low-cost process <b>2016</b> ,		1
37	Insight into photon conversion of Nd <sup>3+</sup> doped low temperature grown p and n type tin oxide thin films. <i>RSC Advances</i> , <b>2016</b> , 6, 67157-67165	3.7	11
36	First Solar Cells on Exfoliated Silicon Foils Obtained at Room Temperature by the SLIM-Cut Technique Using an Epoxy Layer. <i>IEEE Journal of Photovoltaics</i> , <b>2016</b> , 6, 1115-1122	3.7	10
35	Incorporation of dopant impurities into a silicon oxynitride matrix containing silicon nanocrystals. <i>Journal of Applied Physics</i> , <b>2016</b> , 119, 174303	2.5	2
34	The New Copper Composite of Pastes for Si Solar Cells Front Electrode Application. <i>Energy Procedia</i> , <b>2016</b> , 92, 962-970	2.3	8

33	Structural, electrical and optical properties of sprayed Nd <sup>3+</sup> codoped ZnO thin films. <i>Journal of Sol-Gel Science and Technology</i> , <b>2015</b> , 73, 557-562	2.3	11
32	Deposition Time Effect on the Physical Properties of Cu <sub>2</sub> ZnSnS <sub>4</sub> (CZTS) Thin Films Obtained by Electrodeposition Route onto Mo-coated Glass Substrates. <i>Energy Procedia</i> , <b>2015</b> , 84, 127-133	2.3	18
31	Understanding Phenomena of Thin Silicon Film Crystallization on Aluminium Substrates. <i>Energy Procedia</i> , <b>2015</b> , 84, 156-164	2.3	2
30	Structural, optical, spectroscopic and electrical properties of Mo-doped ZnO thin films grown by radio frequency magnetron sputtering. <i>Thin Solid Films</i> , <b>2014</b> , 566, 61-69	2.2	24
29	Efficient energy transfer from ZnO to Nd <sup>3+</sup> ions in Nd-doped ZnO films deposited by magnetron reactive sputtering. <i>Journal of Materials Chemistry C</i> , <b>2014</b> , 2, 9182-9188	7.1	24
28	Optical and structural properties of Nd doped SnO <sub>2</sub> powder fabricated by the sol-gel method. <i>Journal of Materials Chemistry C</i> , <b>2014</b> , 2, 8235-8243	7.1	68
27	Luminescent Properties and Energy Transfer in Pr <sup>3+</sup> Doped and Pr <sup>3+</sup> -Yb <sup>3+</sup> Co-doped ZnO Thin Films. <i>Journal of Physical Chemistry C</i> , <b>2014</b> , 118, 13775-13780	3.8	24
26	Charge Trapping in Hafnium Silicate Films with Modulated Composition and Enhanced Permittivity. <i>Advanced Materials Research</i> , <b>2013</b> , 854, 125-133	0.5	1
25	Bigger picture helps Alf Björseth focus on energy and materials projects for the future. <i>MRS Bulletin</i> , <b>2013</b> , 38, 210-211	3.2	
24	Multicrystalline silicon solar cells from RST ribbon process. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , <b>2012</b> , 9, 2092-2096		5
23	Silicon nanostructures in silicon oxynitride for PV application: effect of argon. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , <b>2012</b> , 9, 1878-1883		2
22	Photoluminescence of Nd-doped SnO <sub>2</sub> thin films. <i>Applied Physics Letters</i> , <b>2012</b> , 100, 101908	3.4	42
21	Formation of silicon nanoparticles from high temperature annealed silicon rich silicon oxynitride films <b>2012</b> ,		2
20	Laser processing for thin film crystalline silicon solar cells <b>2012</b> ,		1
19	Laser doping from spin-on sources for selective emitter silicon solar cells <b>2012</b> ,		4
18	Hf-based high-k materials for Si nanocrystal floating gate memories. <i>Nanoscale Research Letters</i> , <b>2011</b> , 6, 172	5	27
17	Effect of ion implantation energy for the synthesis of Ge nanocrystals in SiN films with HfO <sub>2</sub> /SiO <sub>2</sub> stack tunnel dielectrics for memory application. <i>Nanoscale Research Letters</i> , <b>2011</b> , 6, 177	5	14
16	Effect of annealing treatments on photoluminescence and charge storage mechanism in silicon-rich SiN <sub>x</sub> :H films. <i>Nanoscale Research Letters</i> , <b>2011</b> , 6, 178	5	31

15	Silicon Nanoclusters Embedded into Oxide Host for Non-Volatile Memory Applications. <i>ECS Transactions</i> , <b>2011</b> , 35, 37-45	1	2
14	Ultra-Low Energy Ion Implantation of Si into HfO <sub>2</sub> and HfSiO-based Structures for Non Volatile Memory Applications. <i>Materials Research Society Symposia Proceedings</i> , <b>2010</b> , 1250, 1		
13	Correlation of structural properties with energy transfer of Eu-doped ZnO thin films prepared by sol-gel process and magnetron reactive sputtering. <i>Journal of Applied Physics</i> , <b>2010</b> , 107, 123522	2.5	53
12	Ultra-Low energy Ion Implantation of Si into HfO <sub>2</sub> -based layers for Non Volatile Memory Applications. <i>Materials Research Society Symposia Proceedings</i> , <b>2009</b> , 1160, 1		1
11	Optical properties of ZnO thin films prepared by sol-gel process. <i>Microelectronics Journal</i> , <b>2009</b> , 40, 239-248		40
10	Structural and photoluminescence properties of ZnO thin films prepared by sol-gel process. <i>Journal of Applied Physics</i> , <b>2008</b> , 104, 113539	2.5	50
9	Advanced Inorganic Materials for Photovoltaics. <i>MRS Bulletin</i> , <b>2007</b> , 32, 211-218	3.2	61
8	Influence of the Ge Dose in Ion-implanted SiO <sub>2</sub> Layers on the Related Nanocrystal-memory Properties. <i>Materials Research Society Symposia Proceedings</i> , <b>2006</b> , 933, 1		
7	Polysilicon Films Formed On Alumina By Aluminium Induced Crystallization Of Amorphous Silicon. <i>Materials Research Society Symposia Proceedings</i> , <b>2006</b> , 910, 1		3
6	Rapid Thermal Dopants Diffusion and Surface Passivation for Silicon Solar Cells Applications. <i>Materials Research Society Symposia Proceedings</i> , <b>1996</b> , 429, 127		
5	Silicon Thin Film Homoepitaxy by Rapid Thermal Atmospheric-Pressure Chemical Vapor Deposition (RT-APCVD). <i>Materials Research Society Symposia Proceedings</i> , <b>1996</b> , 429, 367		1
4	Phosphorous Gettering by Rapid Thermal Processing. <i>Materials Research Society Symposia Proceedings</i> , <b>1992</b> , 262, 987		
3	High Energy Heavy Ions Irradiation of Thermal SiO <sub>2</sub> Films on Si. <i>Materials Research Society Symposia Proceedings</i> , <b>1992</b> , 279, 141		2
2	Photooxidation Of Implanted Silicon With Pulsed UV-Laser In Liquid Phase Regime <b>1989</b> , 1022, 153		
1	Phosphorus Doping into Silicon Using ArF Excimer Laser. <i>Materials Research Society Symposia Proceedings</i> , <b>1989</b> , 158, 281		